

Penetration depth measurements in URu₂Si₂
Geometric factors and fitting by a two-band model with chiral
d-wave gap symmetry

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Summer Seminar, Matsuda Lab.

“Soutenance de stage d'option scientifique”, Ecole Polytechnique

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 - Principle of Calibration
 - An intuitive approach
 - A computational approach
 - Final (“easy”) solution
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 - Two-band superfluid density: the semiclassical model
 - Applying to our model of URu₂Si₂
 - Fitting data
- 4 Acknowledgements, Bibliography

Tunnel diode oscillator

First proposed by van Degrift, 1981 for high precision measurements of resonance frequency, sample inserted into the primary coil.

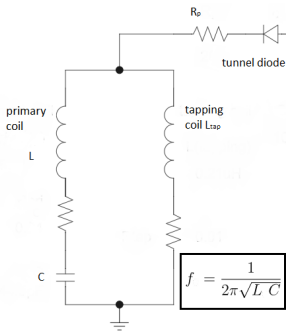


Figure: oscillating circuit, part of the low-T electronics

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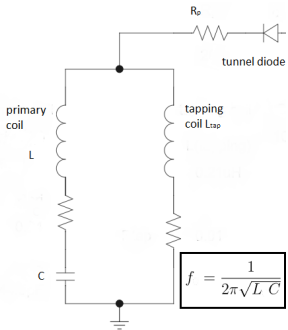
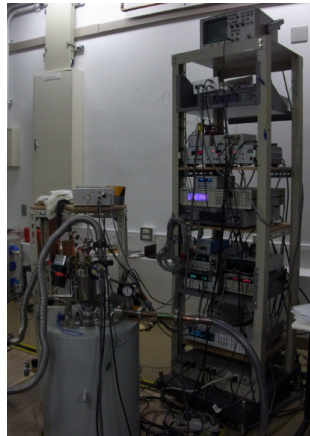


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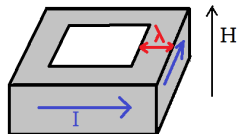
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How can we relate the resonance frequency and λ ?

- start with magnetic energy of coil (SI)

$$U = \frac{1}{2}LI^2 = \frac{1}{2} \int \vec{B} \cdot \vec{H} d^3r$$

$$\Delta U = \frac{1}{2}(L_s - L_0)I^2 = \frac{1}{2} \int \mu_0 \vec{M} \cdot \vec{H}_0 d^3r$$

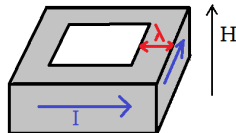


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$$\frac{f_s - f_0}{f_0} = \frac{1}{2} \frac{L_s - L_0}{L_0}$$

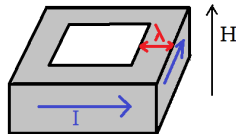


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Resulting frequency change with temperature

$$f(T) - f(T_{min}) = -\frac{f_0}{2V_c} \int_{V_s} \frac{M(\lambda(T), H_0) - M(\lambda(T_{min}), H_0)}{H_0} d^3r$$

$M(\lambda)$ following Chia, 2004, Prozorov et al., 2000

- ① take into account the **the demagnetizing effect**

$$M = \frac{\chi}{1 + N\chi} H_{\text{applied}}$$

An intuitive approach

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Demagnetizing factor N , (see [Brandt, 2001a])

Strictly defined only for ellipsoids (homogeneous M)

$$H_{\text{intern}} = H_{\text{applied}} - NM(H_{\text{intern}}; N = 0)$$

$$M(H_{\text{intern}}; N = 0) = M(H_{\text{applied}}; N)$$

$$M(H_{\text{intern}}; N = 0) = \chi H_{\text{intern}}$$

An effective demagnetizing factor can also be defined (via average magnetization) for other shapes.

See Refs. [Osborn, 1945] for the general ellipsoid, [Chen et al., 1991] for cylinders, or [Pardo et al., 2004] for rectangular prisms.

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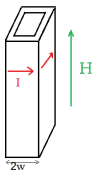
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$$\chi = M/H = \left[1 - \frac{\lambda}{w} \tanh\left(\frac{w}{\lambda}\right) \right]$$

$$\chi \approx - \left[1 - \frac{\lambda}{w} \right]$$



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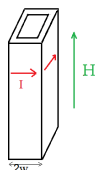
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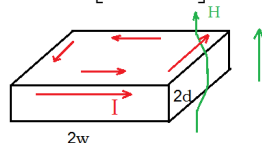
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For a finite sample an effective dimension can be introduced [Prozorov et al., 2000]

$$\chi \approx - \left[1 - \frac{\lambda}{R_{3D}} \right]$$



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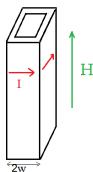
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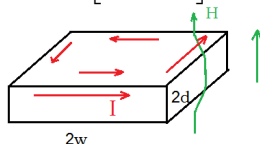


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- 3 We linearize:

$$M = \frac{\chi}{1 - N} H$$



An intuitive approach

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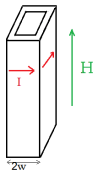
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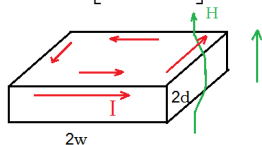
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resulting magnetization

$$M = - \frac{H}{1 - N} \left[1 - \frac{\lambda}{R_{3D}} \right]$$

Conclusion for “Prozorov-G-factor”

Summary until now

$$f(T) - f(T_{min}) = -\frac{f_0}{2V_c} \int_{V_s} \frac{M(\lambda(T), B_0) - M(\lambda(T_{min}), B_0)}{H_0} d^3r$$

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By putting everything together

$$G = \frac{2(1-N)R_{3D}}{f_0} \frac{V_c}{V_s} \text{ so that } \Delta\lambda = G\Delta f$$

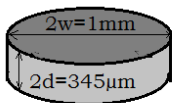
- demagnetizing factor
 $0 < N < 1$
- effective dimension
 $0.2w < R_{3D} < 0.5w$
- filling factor V_s/V_c

An intuitive approach

How to test this approach?

Sample dependence

$$G \propto \frac{(1 - N)R_{3D}}{V_s}$$

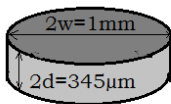


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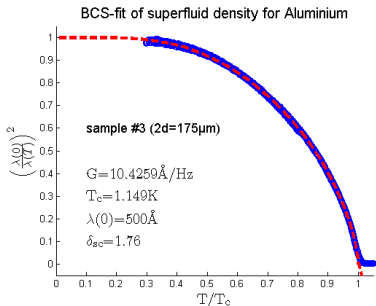
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2d=175μm

2d=55μm



$$\frac{\lambda(T)}{\lambda(0)} =$$

$$\left[\frac{\Delta(T)}{\Delta(0)} \tanh \frac{\Delta(T)}{\Delta(0)} \frac{\delta_{sc} T_c}{2T} \right]^{-1/3}$$

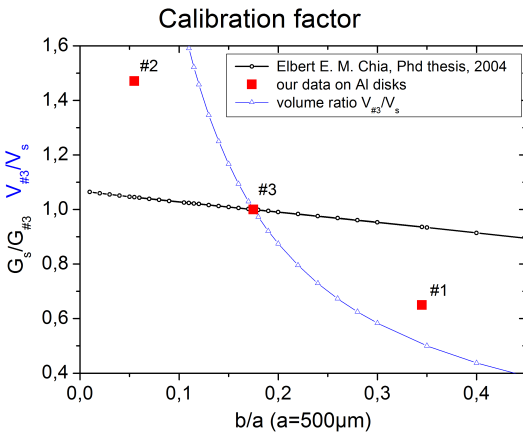
$$\frac{\Delta(T)}{\Delta(0)} = \tanh \left(\frac{\pi}{\delta_{sc}} \sqrt{a \left(\frac{T_c}{T} - 1 \right)} \right)$$

where: $\Delta(0) = \delta_{sc} k_B T_c$

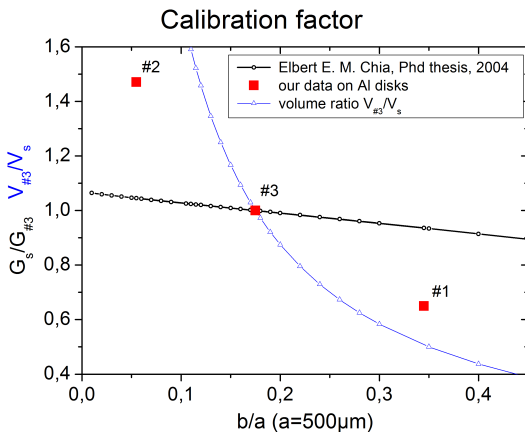
[Tinkham, 1996, Prozorov and Giannetta, 2006]

An intuitive approach

Testing this approach



Testing this approach



Something is wrong...

Demagnetizing effects exist but are greatly overestimated!

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A computational approach

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Method developed by Brandt (see e.g. [Brandt and Miktik, 2000, Brandt, 2001b]) for 1-dimensional problems (cylinder,...)

the basic equations (London)

$$-\lambda^2 \mu_0 \vec{j} = \vec{A} = \vec{A}_j + \vec{A}_a \quad (1)$$

$$\mu_0 \vec{j} = -\nabla^2 \vec{A}_j \quad (2)$$

- A_a comes from the applied field H_a .
 $A_a = -\frac{r}{2} \mu_0 H_a$ for the disk case.
- A_j comes from the shielding currents. (Eq. 2)

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$$A_a = -\frac{r}{2} \mu_0 H_a = \mu_0 \int d^2 r' [Q_{cyl}(\vec{r}, \vec{r}') - \lambda^2 \delta(\vec{r} - \vec{r}')] j(\vec{r}')$$

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- 3 Solve this equation numerically on a grid.

Compute on a grid...

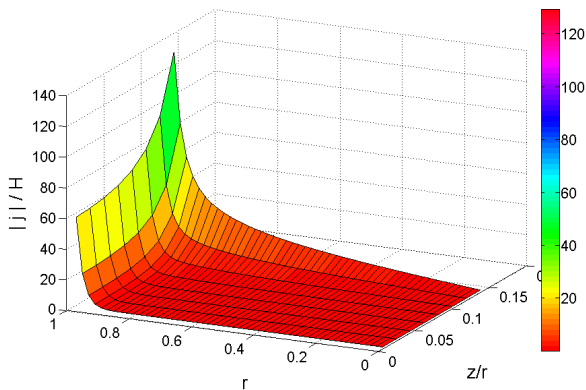
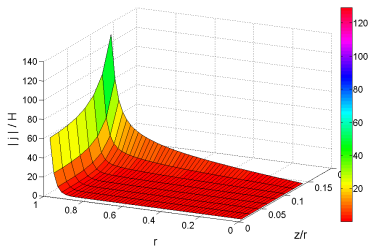


Figure: Example of a simulation for a disk with radius $r = 1$, half-height $d = 0.15$, $\lambda = 0.1$ on a small grid with 480 equally spaced gridpoints

A computational approach

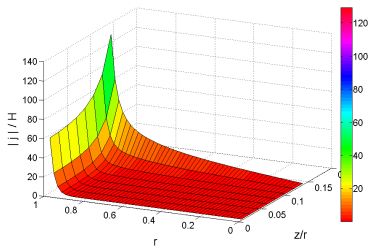
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$$-\frac{r}{2}\mu_0 H_a = \mu_0 \int d^2r' [Q_{\text{cyl}}(\vec{r}, \vec{r}') - \lambda^2 \delta(\vec{r} - \vec{r}')] j(\vec{r}')$$

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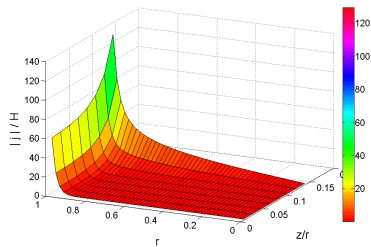


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A computational approach

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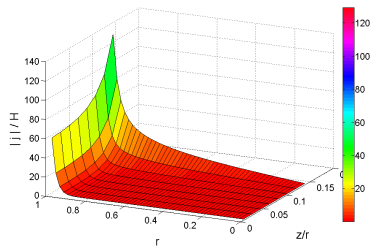
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- $-\frac{r_i}{2} H_a = \sum_j w_j \left(Q_{ij} - \lambda^2 \frac{\delta_{ij}}{w_i} \right) j_j$

A computational approach

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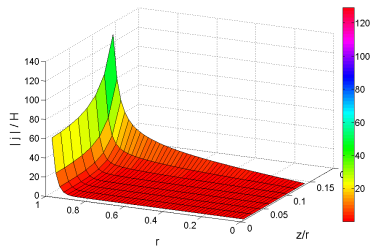
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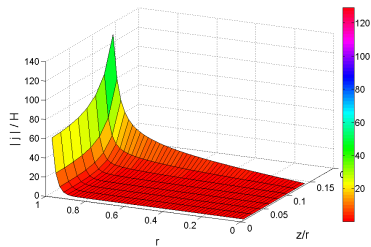
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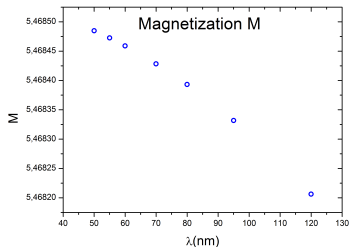
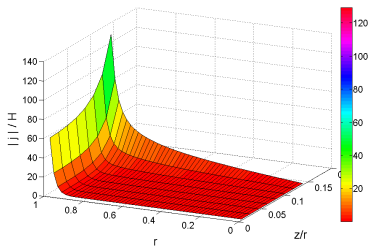
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- $\frac{j_i}{H_a} = \frac{1}{2} \sum_j (\tilde{Q}^{-1})_{ij} r_j$
- $\frac{M}{H} = \sum_i r_i^2 \frac{j_i}{H} w_i$

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Compute on a grid...



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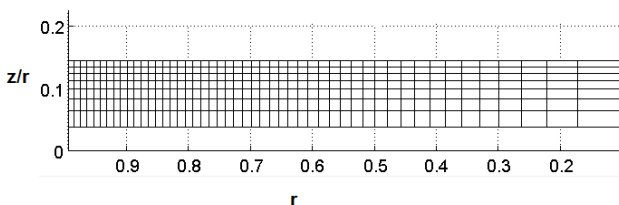
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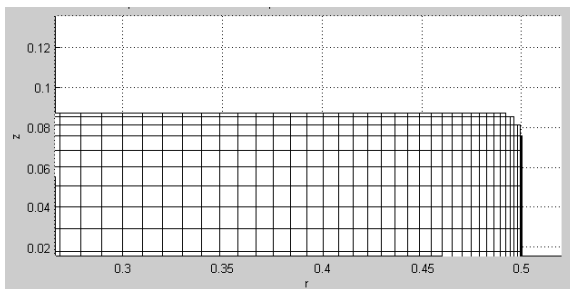


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Remove corner points to model realistic corners

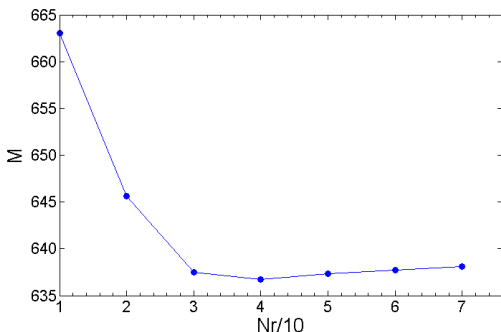


Some problems and some solutions

- Use a grid that gets finer at the borders (unequal weights)
- Remove corner points to model realistic corners
- M still depends on the number of grid points.

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- M still depends on the number of grid points.
Use the same number of gridpoints for all computations, hope for obtaining relative G-factors.



Some problems and some solutions

- Use a grid that gets finer at the borders (unequal weights)
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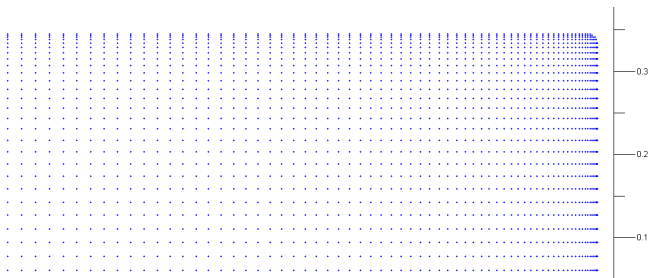
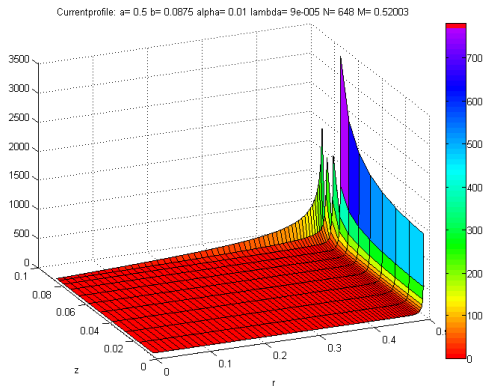


Figure: Example of the final grid with ~ 2000 gridpoints

Some problems and some solutions

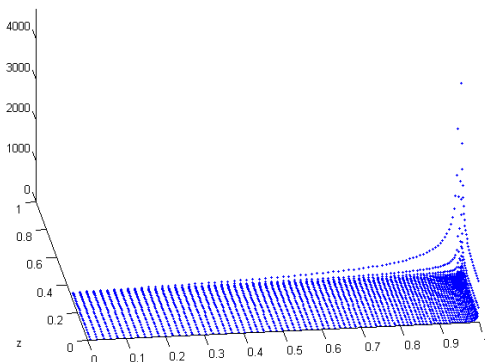
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Current profile: $a=1$ $b=0.345$ $\alpha=0.01$ $\lambda=0.0001$ $N=2534$ $M=5.4685$



Results of computational approach for Al-disks

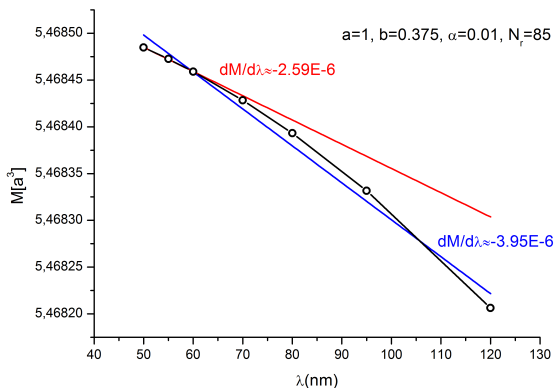
$$f(T) - f(T_{min}) = -\frac{f_0}{2V_c} \left(\int_{V_s} M(\lambda(T), H_0)/H_0 d^3r - \int_{V_s} M(\lambda(T_{min}), H_0) \right)$$

$$f(T) - f(T_{min}) \approx \frac{f_0}{2V_c} V_s \frac{dM}{d\lambda} (\lambda(T_{min}) - \lambda(T))/H_0$$

Let's approximate $\frac{dM}{d\lambda}$ as the slope of a linear fit

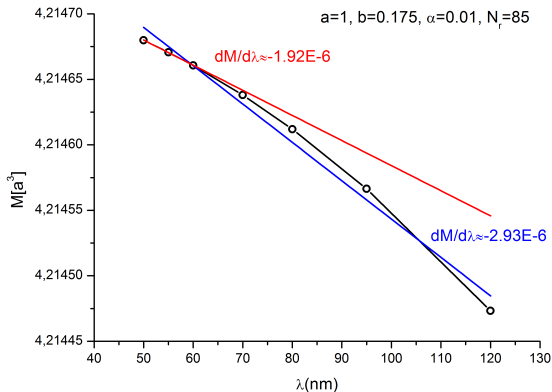
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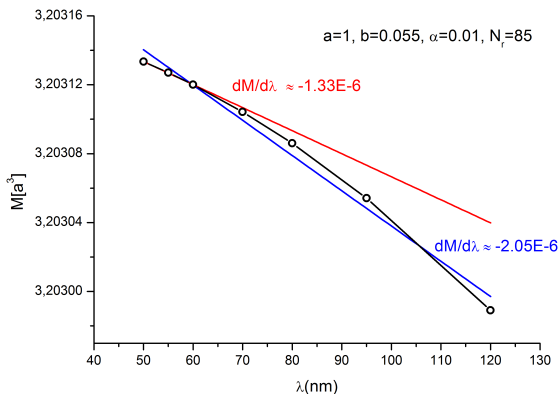
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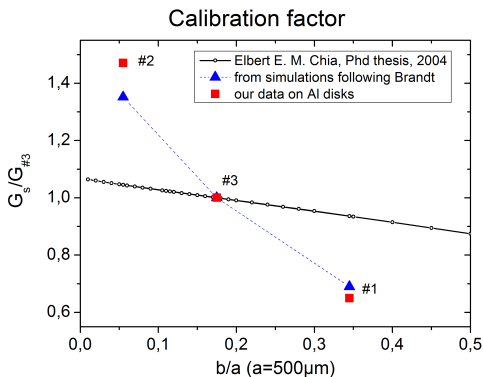
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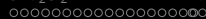
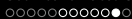


Results of computational approach for Al-disks

Check obtained relative G-factors



- Reasonable agreement!
- However, absolute values cannot be reproduced.



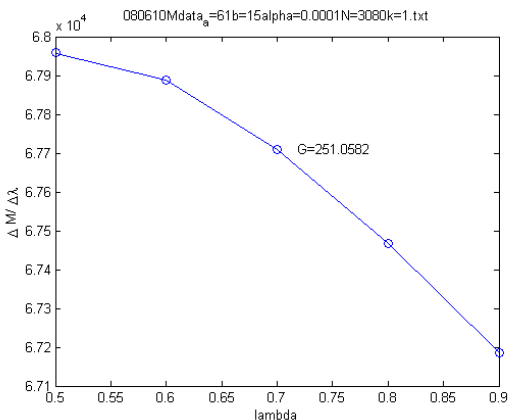
A computational approach

Trying on the URu₂Si₂-samples

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#E2_A: $G = 250 \text{ \AA/Hz}$ found, $G \approx 200 \text{ \AA/Hz}$ probably correct!

#E2: $G = 52$ (or 79) \AA/Hz found, $G \approx 80 \text{ \AA/Hz}$ probably correct!



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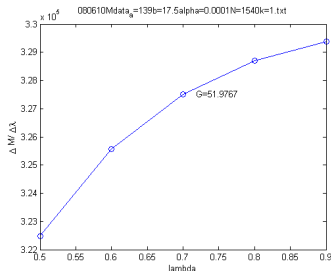
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$\frac{dM}{d\lambda}$ for λ appropriate for URu₂Si₂:

$$G_U = 52$$

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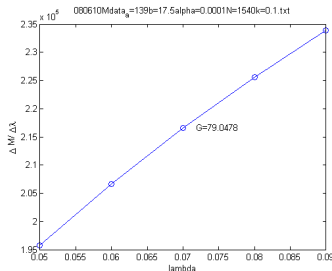
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$\frac{dM}{d\lambda}$ for λ appropriate for Aluminium:

$$G_{Al} = 79!$$

Final ("easy") solution

Adapted final solution



Final ("easy") solution

Adapted final solution

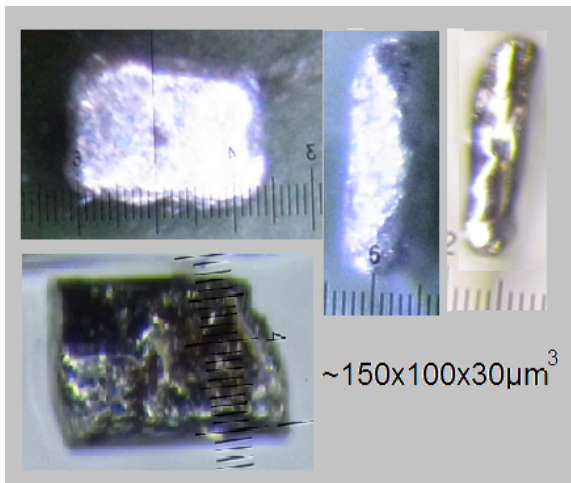
Cut an Al-sample of the same size/shape as our best URu₂Si₂-sample (#E2_B)



Final ("easy") solution

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Final ("easy") solution

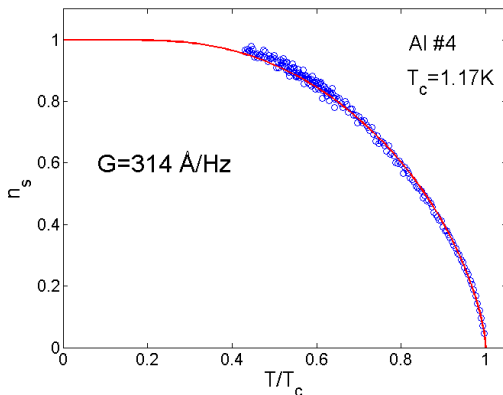
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Cut an Al-sample of the same size/shape as our best URu₂Si₂-sample (#E2_B) and measure it:

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URu₂Si₂

- Hidden order transition at $T_h = 17.5\text{K}$
- Superconducting below 1.4K

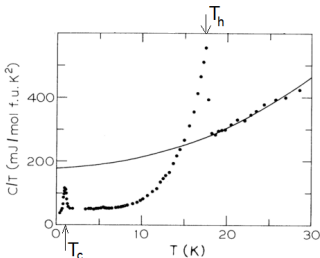


Figure: taken from Ref. [Palstra et al., 1985]

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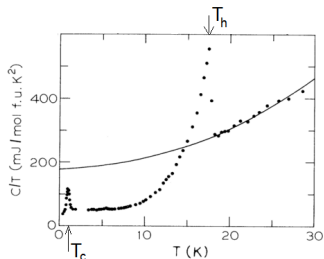


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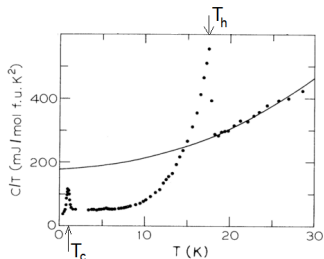
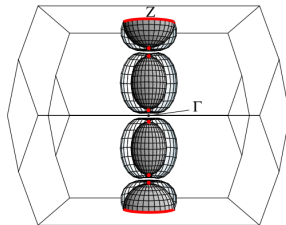


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Hidden order: We don't know the Brillouin-zone, FS not clear

- Thermal conductivity measurements by Kasahara et al.
- Specific heat measurements by Yano et al.

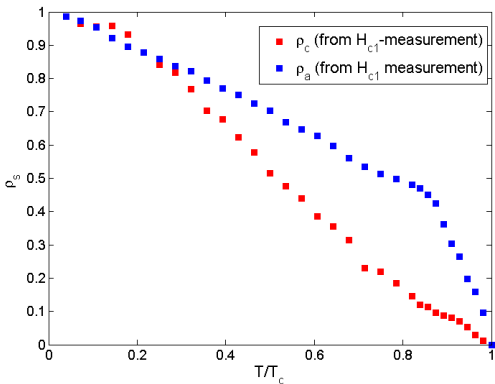
$$\Delta_k \propto k_z(k_x + ik_y) \text{ (chiral d-wave)}$$



H_{c1} and mysterious kink

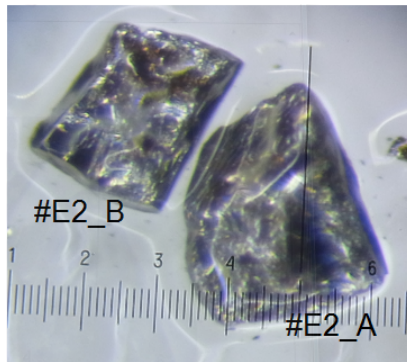
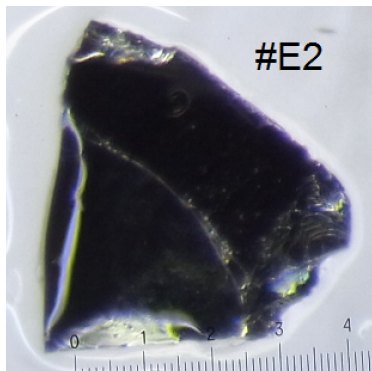
See [Okazaki et al., 2009]

Superfluid density extracted from H_{c1}



Our samples

- ultraclean ($RRR \sim 700$)
- Cut one larger crystal into two.



Experimental

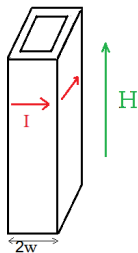
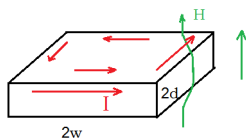
How to get $\Delta\lambda_{ab}$ and $\Delta\lambda_c$

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Measure frequency shift in 2 different geometries:

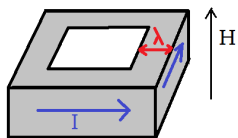
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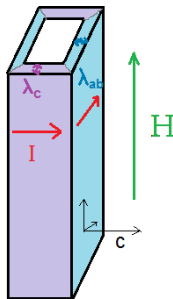
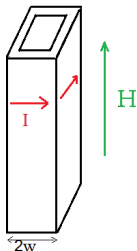


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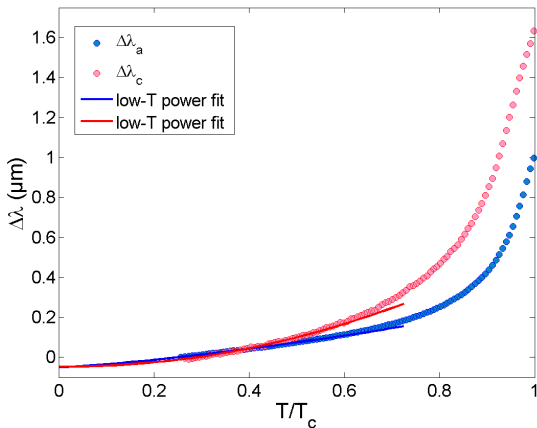
$$\Delta\lambda_{ab} = G\Delta f_{H||c}$$



$$\Delta f_{H||a} = \frac{f_0 V_s}{2V_c} \left(\frac{\Delta\lambda_{ab}}{d} + \frac{\Delta\lambda_c}{w} \right)$$

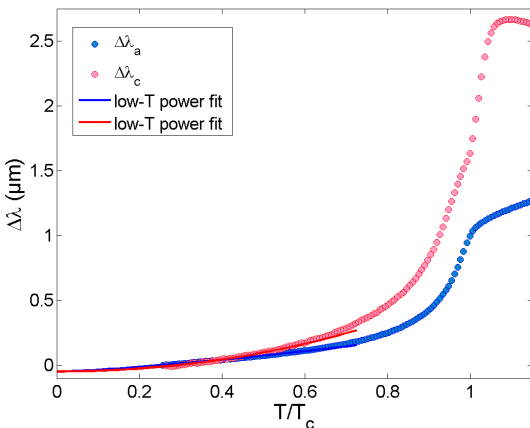
Result

We can find the change in penetration depth:



Result

We can find the change in penetration depth:
But strangely we get different critical temperatures.



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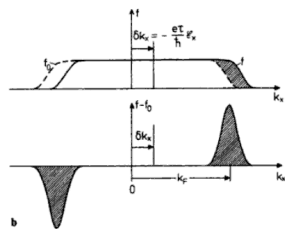
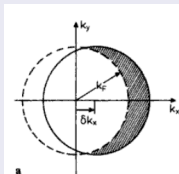
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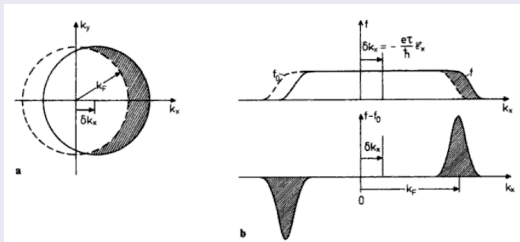
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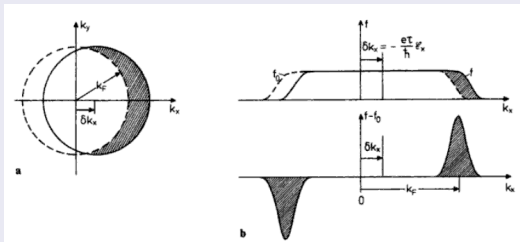
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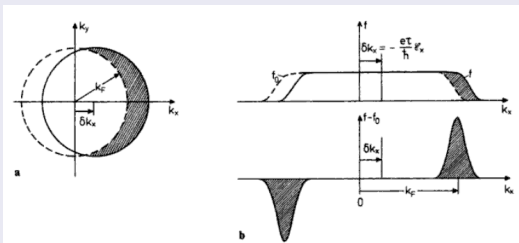
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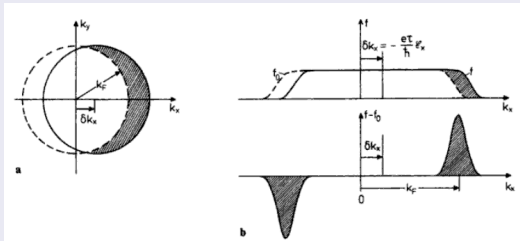
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For (quasi)free electrons and isotropic τ we find Drude: $\sigma = \frac{ne^2\tau}{m^*}$

Two-band superfluid density: the semiclassical model

Let's do the same for the supercurrent

[Chandrasekhar and Einzel, 1993]

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Normal conductivity

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London equations:

$$m \vec{v}_s = -e \vec{A}$$

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- Supercurrent: $\vec{j}_s \propto - \int d^3k \left[- \left(\frac{\partial n_k}{\partial \epsilon_k} - \frac{\partial f(E_k)}{\partial E_k} \right) \right] (\vec{v}_k \vec{v}_k) \cdot \vec{A}$

n_k is the single particle occupation of the state k

$f(E_k)$ is its occupation by quasiparticles. $E_k = \sqrt{\epsilon_k^2 + \Delta_k^2}$

Only superconducting electrons contribute to j_s .

Two-band superfluid density: the semiclassical model

How do we get the superfluid-density now?

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We use:

$$d^3k = \frac{dS_F d\epsilon_k}{\hbar v_F}$$

$$d\epsilon_k = 2 \frac{d\epsilon_k}{dE_k} dE_k$$

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- **First (diamagnetic) term:** $\oint dS_F \frac{\vec{v}_F \vec{v}_F}{v_F}$
- **Second (paramagnetic) term:** $\oint dS_F \frac{\vec{v}_F \vec{v}_F}{v_F} 2 \int \frac{d\epsilon_k}{dE_k} dE_k \frac{\partial f(E_k)}{\partial E_k}$

We use:

$$d^3k = \frac{dS_F d\epsilon_k}{\hbar v_F}$$

$$d\epsilon_k = 2 \frac{d\epsilon_k}{dE_k} dE_k$$

Two-band superfluid density: the semiclassical model

How do we get the superfluid-density now?

$$\vec{j}_s \propto - \int d^3k \left[- \left(\frac{\partial n_k}{\partial \epsilon_k} - \frac{\partial f(E_k)}{\partial E_k} \right) \right] (\vec{v}_k \vec{v}_k) \cdot \vec{A}$$

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Final result $\mu_0 \vec{j} = -\lambda^{-2} \vec{A}$ [Prozorov and Giannetta, 2006]

$$\lambda_{ij}^{-2}(T) = \frac{\mu_0 e^2}{4\pi^3 \hbar} \oint_{FS} dS_k \left[\frac{v_F^i v_F^j}{|v_F|} \left(1 + 2 \int_{\Delta(k)}^{\infty} dE_k \frac{\partial f(E_k)}{\partial E_k} \frac{N(E_k)}{N(0)} \right) \right]$$

(Only!) for quasi-free electrons and “simple” geometry we find

$$\lambda(0)^{-2} = \frac{\mu_0 n e^2}{m^*}$$

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We can now compute the superfluid density

$$\rho_{ii} = \left(\frac{\lambda_{ii}(0)}{\lambda_{ii}(T)} \right)^{-2}$$

Applying to our model of URu₂Si₂

What does it look like in our case?

$$\lambda_{ij}^{-2}(T) = \frac{\mu_0 e^2}{4\pi^3 \hbar} \oint_{FS} dS_k \left[\frac{v_F^i v_F^j}{|v_F|} \left(1 + 2 \int_{\Delta(k)}^{\infty} dE_k \frac{\partial f(E_k)}{\partial E_k} \frac{N(E_k)}{N(0)} \right) \right]$$

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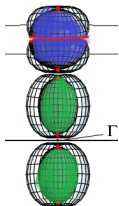
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a little scary.

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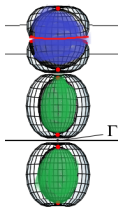
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Applying to our model of URu₂Si₂

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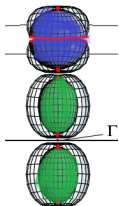


- Contributions from **electron-** and **hole-**FS cannot be separated in general.
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Applying to our model of URu₂Si₂

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Applying to our model of URu₂Si₂

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Using H_{c2}

$$H_{c2} = \frac{\Phi_0}{2\pi\xi^2}$$

$$\xi = \frac{\hbar v_F}{\pi\Delta}$$

We need: $\frac{v_{F,e}^a}{v_{F,h}^a}$, $\frac{v_{F,e}^c}{v_{F,e}^a}$

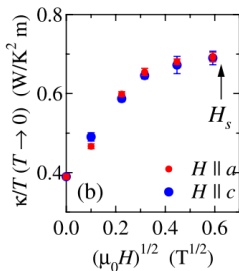
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- use the “virtual upper critical field” (see [Kasahara et al., 2007]) for the light hole band
- Correct for the size of gaps

$$\frac{v_{F,e}^a}{v_{F,h}^a} = \sqrt{\frac{H_s}{H_{c2}^{H||a}} \frac{\Delta_{0,e}}{\Delta_{0,h}}}$$

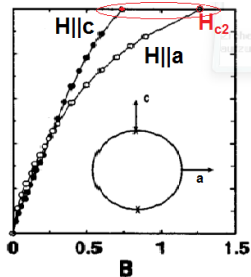
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$$\frac{v_{F,e}^a}{v_{F,h}^a} = \sqrt{\frac{H_s}{H_{c2}^{H||a}} \frac{\Delta_{0,e}}{\Delta_{0,h}}}$$

- Correct for point nodes in the electron FS (see [Miranović et al., 2001])

$$\frac{v_{F,e}^c}{v_{F,e}^a} = \frac{H_{c2}^{H||a}}{H_{c2}^{H||c}} \cdot 1.66$$

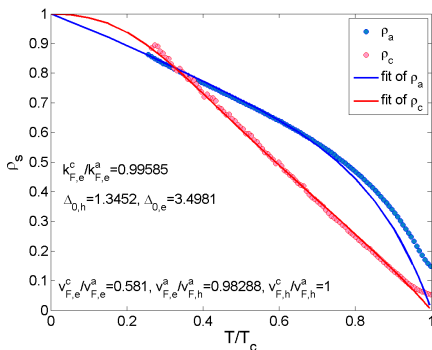
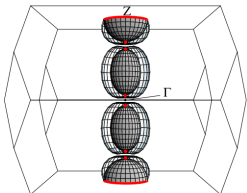
Let's apply this to data

Parameters needed:

- Shape of FS: $\frac{k_{F,c}^h}{k_{F,a}^h}$, $\frac{k_{F,c}^e}{k_{F,a}^e}$
- Anisotropy of v_F for each FS
- Ratio of v_F of the 2 bands

Fitting parameters:

- Gapvalues Δ_0 (α -model)
- anisotropy of e-FS



And a different gap structure?

Try to find the nodal structure in a 2-band model with equal volume of the FS's
vspace10cm

Fitting data

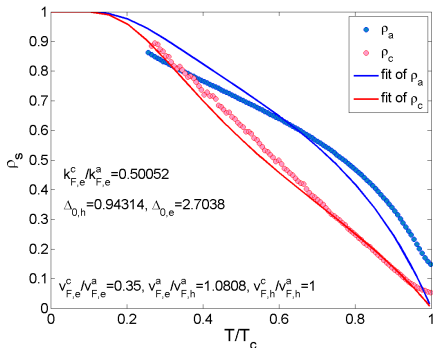
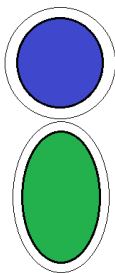
And a different gap structure?

Try to find the nodal structure in a 2-band model with equal volume of the FS's

Both isotropic s-wave

$$\Delta_h = \Delta_h(T)$$

$$\Delta_e = \Delta_e(T)$$



Fitting data

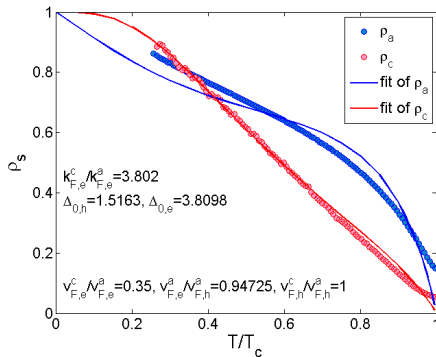
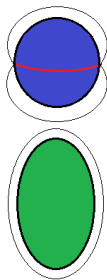
And a different gap structure?

Try to find the nodal structure in a 2-band model with equal volume of the FS's

hole-FS: only line node, electron-FS: fully gapped

$$\Delta_h = \Delta_h(T) \cos(\theta)$$

$$\Delta_e = \Delta_e(T)$$



Fitting data

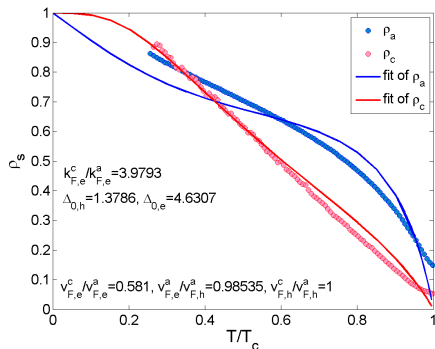
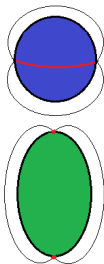
And a different gap structure?

Try to find the nodal structure in a 2-band model with equal volume of the FS's

hole-FS: line node, electron-FS: point nodes

$$\Delta_h = \Delta_h(T) \cos(\theta)$$

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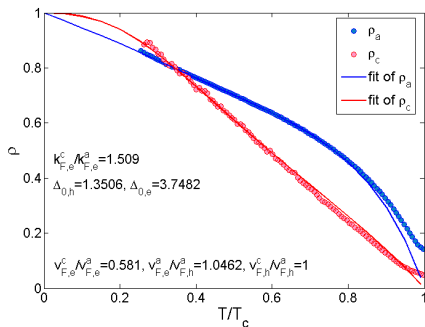
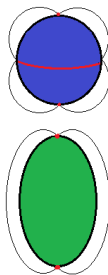
And a different gap structure?

Try to find the nodal structure in a 2-band model with equal volume of the FS's

hole-FS: line node and point nodes, electron FS: point nodes

$$\Delta_h = \Delta_h(T) 2 \cos(\theta) \sin(\theta)$$

$$\Delta_e = \Delta_e(T) \sin(\theta)$$



Fitting data

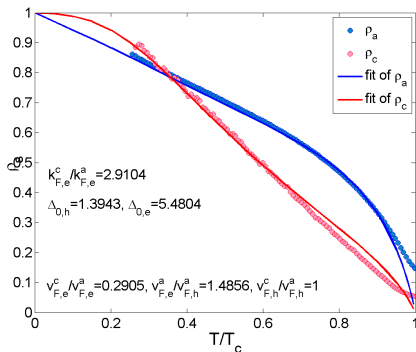
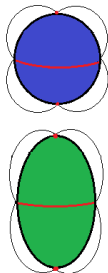
And a different gap structure?

Try to find the nodal structure in a 2-band model with equal volume of the FS's

Both line node and point nodes

$$\Delta_h = \Delta_h(T) 2 \sin(\theta) \cos(\theta)$$

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Fitting data

What about Fermi-liquid corrections?

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Predicted behaviour: [Varma et al., 1986]

$$\lambda^{-2}(T) = \frac{\mu_0 n e^2}{m_d} \left[1 - \frac{(1 + F_1^s/3) Y(T)}{1 + (F_1^s/3) Y(T)} \right]$$

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- m_d : dynamic mass, for example from cyclotron resonance
- F_1^s Landau coefficient
- $Y(T)$ is the Yosida function, $N(0)^{-1} \sum_k dn/dE_k$

What about Fermi-liquid corrections?

Limiting behaviour: [Varma et al., 1986]

$$\lambda^{-2}(T) = \frac{m}{m_d} \lambda_{BCS}^{-2}(T), \quad T \rightarrow 0$$

$$\lambda^{-2}(T) = \frac{m}{m^*} \lambda_{BCS}^{-2}(T), \quad T \rightarrow T_c$$

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We estimate $\lambda(0)$ using cyclotron resonance mass.

$$\lambda(0) = \left(\frac{\mu_0 n e^2}{m_d} \right)^{-1/2}$$

We get $\lambda_a(0) = 0.66 \mu m$ and $\lambda_c(0) = 0.5 \mu m$, smaller than $\lambda \approx 1 \mu m$ from μ SR and $\lambda_a(0) > \lambda_c(0)$ in contrast to H_{c1} -measurements.

May Fermi-liquid corrections play a role?

$$\lambda^{-2}(T) = \frac{\mu_0 n e^2}{m_d} \left[1 - \frac{(1 + F_1^s/3)Y(T)}{1 + (F_1^s/3)Y(T)} \right]$$

Generalize this to include bandstructure (*quite* a long formula)

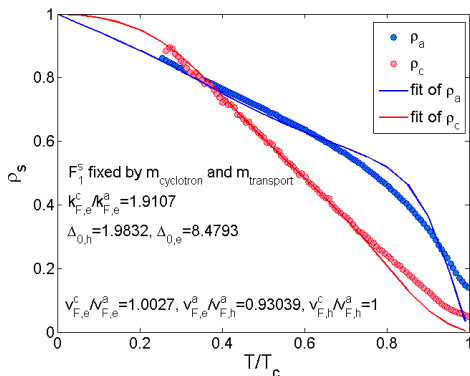
Fitting data

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The F_1^s fixed by mass ratios m^*/m_d , all other parameters free



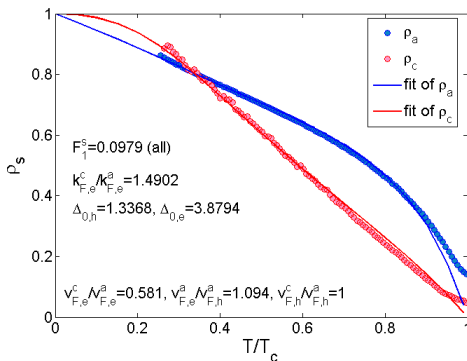
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Fit F_1^s starting from 0



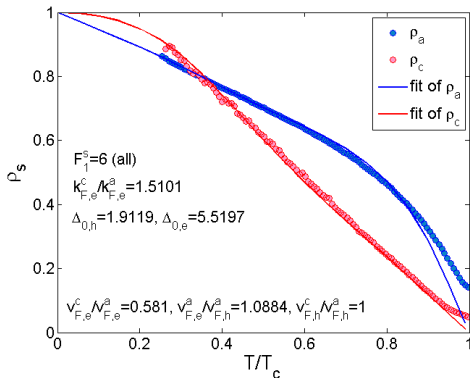
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Generalize this to include bandstructure (*quite* a long formula)

Set all $F_1^s = 6$

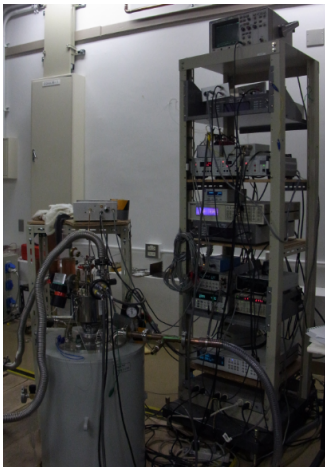


Fitting data

Some conclusions

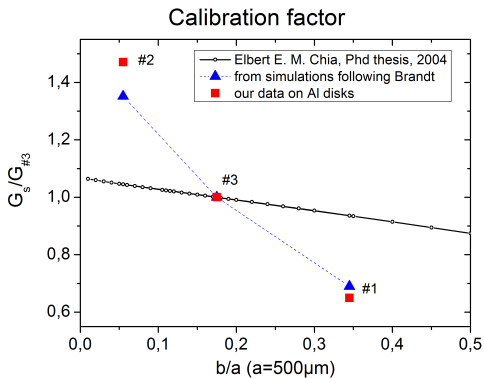
Some conclusions

- The temperature dependent penetration depth can be measured accurately with TDO technique



Some conclusions

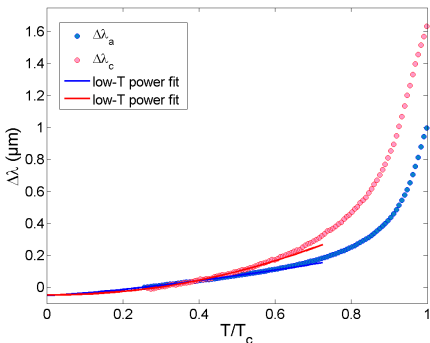
- The temperature dependent penetration depth can be measured accurately with TDO technique
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Fitting data

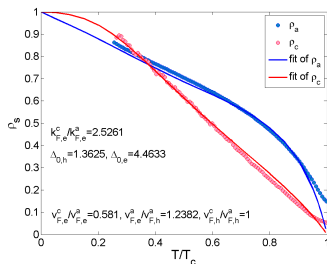
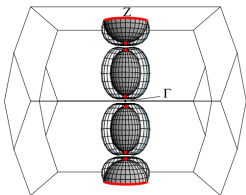
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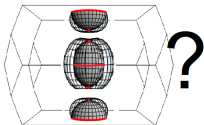
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- We can reliably extract the superfluid density ρ_a and ρ_c of URu₂Si₂
- The data can be reasonably well fitted by the two band model with $k_z(k_x + ik_y)$ gap symmetry of Kasahara et al., 2007
- A gap structure with less nodes does not fit the data well
- FL-corrections possibly play a role in the T-dependance of λ , difficult to be sure
- Unknown Fermi-surface implies many difficulties.



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